



DMN12M3UCA6

# N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>SSS</sub>	$R_{SS(ON)}$ Typ	Is мах Та = +25°С
14.5V	2.36mΩ @ V <sub>GS</sub> = 3.8V	24.4A

## Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{SS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Battery Management
- Load Switch
- Battery Protection

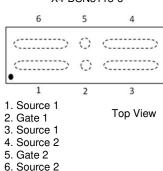
### Features

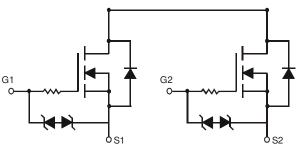
- CSP with Footprint 3.05mm × 1.77mm
- Height = 0.11mm for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Mechanical Data**

- Case: X4-DSN3118-6
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 4
- Weight: 0.0012 grams (Approximate)







Equivalent Circuit

### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN12M3UCA6-7	X4-DSN3118-6	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Notes:

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



J3 = Product Type Marking Code

- YM = Date Code Marking
- Y or  $\overline{Y}$  = Year (ex: H = 2020)
- M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Date Code Rey												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	H		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

### X4-DSN3118-6

<sup>2.</sup> See



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Source-Source Voltage	V <sub>SSS</sub>	14	V		
Gate-Source Voltage	Vgss	±8	V		
Continuous Source Current (Note 5) $V_{GS} = 4.5V$	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	Is	24.4 19.6	А
Continuous Source Current (Note 5) $V_{GS} = 2.5V$	ls	16.4 13.1	А		
Pulsed Source Current (Note 6)	lsм	100	А		

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	1.10	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R <sub>0JA</sub>	114.1	°C/W
Power Dissipation (Note 5)	PD	2.47	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	50.7	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			71				
Source-Source Breakdown Voltage	BVsss	14.5		—	V	$V_{GS} = 0V$ , $I_{S} = 1mA$	
Zero Gate Voltage Drain Current TJ = +25°C	lsss	_	_	1	μA	Vss = 9.6V, Vgs = 0V	
Gate-Source Leakage	IGSS	_	_	±10	μA	$V_{GS} = \pm 8V, V_{SS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.35	0.8	1.4	V	Vss = 10V, Is = 1.41mA	
		1.5	2.27	2.75		$V_{GS} = 4.5V, I_S = 6A$	
Static Source-Source On-Resistance	Descent	1.6	2.36	2.85	mΩ	$V_{GS} = 3.8V, I_{S} = 6A$	
Static Source-Source OII-Resistance	Rss(ON)	1.7	2.54	3.95	1115.2	$V_{GS} = 3.1V, I_S = 6A$	
		1.9	2.9	6.1		V <sub>GS</sub> = 2.5V, I <sub>S</sub> = 6A	
Diode Forward Voltage	Vss	-	0.69	1.2	V	$V_{GS} = 0V, I_S = 6A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	3062	4593			
Output Capacitance	Coss	-	758	1137	pF	Vss = 10V, Vgs = 0V, f = 1kHz	
Reverse Transfer Capacitance	Crss	_	198	297			
Total Gate Charge	Qg	-	45.7	68.6			
Gate-Source Charge	Qgs	-	8.3	12.5	nC	$V_{SS} = 8V, V_{GS} = 4V,$	
Gate-Drain Charge	Qgd	-	16.0	24.0	10	Is = 6A	
Gate Charge at V <sub>TH</sub>	Qg(th)	—	4.5	6.8			
Turn-On Delay Time	tD(ON)	_	1005	1508			
Turn-On Rise Time	t <sub>R</sub>	_	2186	3279	20	$V_{SS} = 8V, V_{GS} = 4V,$	
Turn-Off Delay Time	tD(OFF)	—	2643	3965	ns	I <sub>S</sub> = 6A	
Turn-Off Fall Time	tF		4193	6290			

5. Device mounted on FR-4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu. Notes:

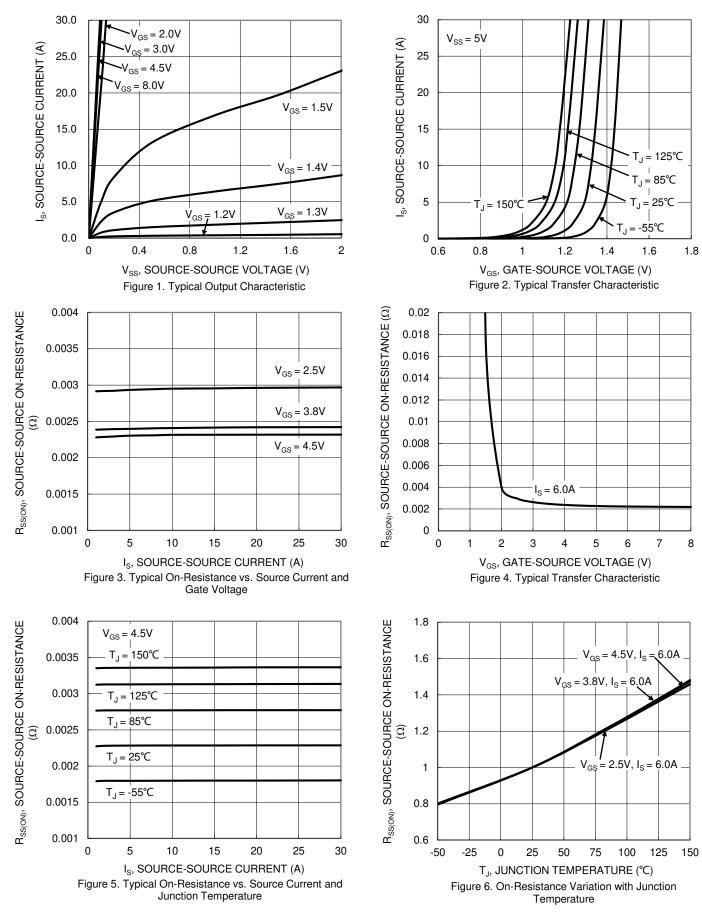
6. Repetitive rating, pulse width limited by junction temperature.
7. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

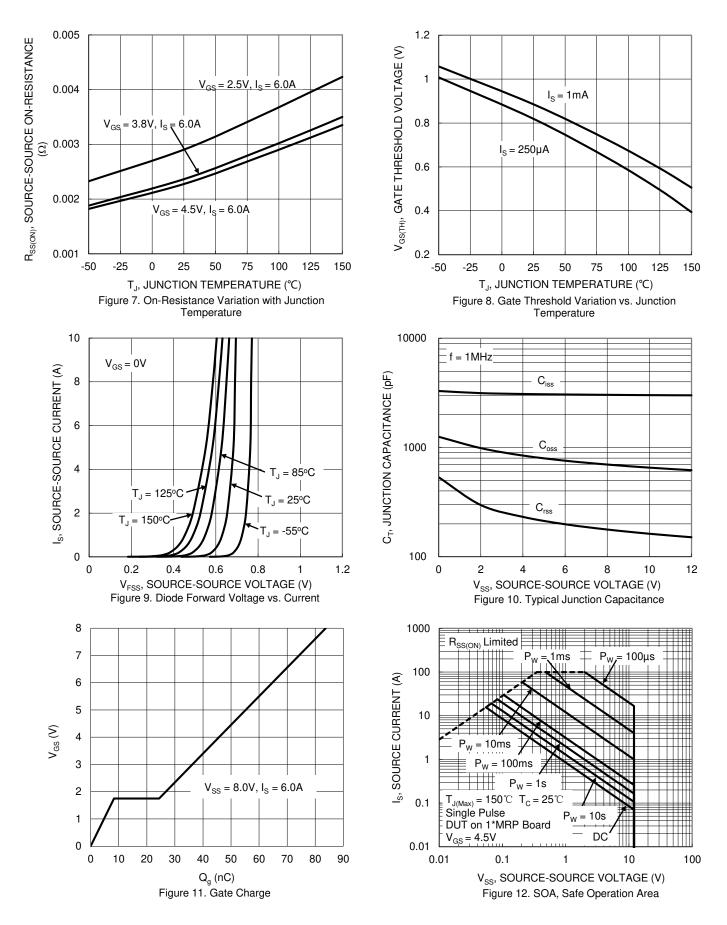


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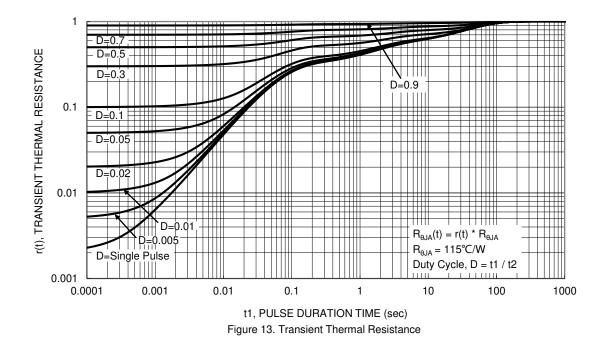




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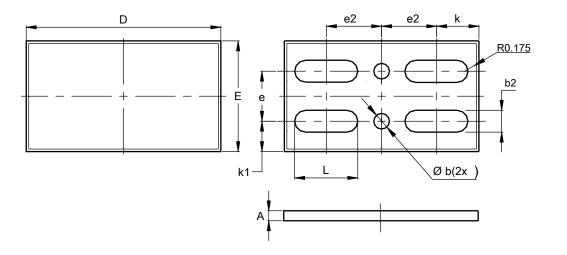




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X4-DSN3118-6

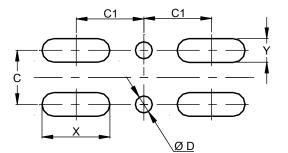


X4-DSN3118-6						
Dim	Min	Max	Тур			
Α	0.09	0.16	0.11			
b			0.25			
b2	0.32	0.38	0.35			
D	3.00	3.10	3.05			
Е	1.72	1.82	1.77			
е			0.800			
e2			0.878			
k			0.648			
k1			0.485			
L	0.975	1.035	1.005			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### X4-DSN3118-6



Dimensions	Value (in mm)
С	0.800
C1	0.878
D	0.250
Х	1.005
Y	0.350



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